# Ultra High Dynamic Range

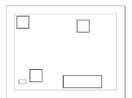
# **Monolithic Amplifier Die**

**PHA-1-D+** 

 $50\Omega$  0.05 to 6 GHz

# The Big Deal

- Ultra High IP3
- Broadband high dynamic range without external matching components



## **Product Overview**

PHA-1-D+ is an advanced wideband amplifier die fabricated using E-pHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PHA-1-D+ has good input and output return loss over a broad frequency range without the need for external matching components.

# **Key Features**

Feature	Advantages
Broad Band: .05 to 6.0 GHz	Broadband covering primary wireless communications bands: Cellular, PCS, LTE, WiMAX
Extremely High IP3 versus DC power Consumption 38.8 dBm typical at 2 GHz	The PHA-1-D+ matches industry leading IP3 performance relative to power consumption. The combination of the design and E-pHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 20 dB above the P1dB point. This feature makes this amplifier ideal for use in:  • Driver amplifiers for complex waveform up converter paths  • Drivers in linearized transmit systems  • Secondary amplifiers in ultra High Dynamic range receivers
No External Matching Components Required	Mini-Circuits PHA-1-D+ provides good Input and Output Return Loss up to 4 GHz without the need for any external matching components
Low Noise Figure: 2.3dB typ. up to 3 GHz 3.6dB typ. up to 6 GHz	A unique feature of the PHA-1-D+ which separates this design from all competitors is the low noise figure performance in combination with the high dynamic range.

# **Monolithic Amplifier Die**

PHA-1-D+

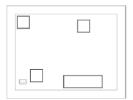
#### $50\Omega$ 0.05 to 6 GHz

#### **Product Features**

- High IP3, 38.8 dBm typ. at 2 GHz, 5V
- Gain, 13.6 dB typ. at 2 GHz, 5V
- High Pout, P1dB 22 dBm typ. at 2 GHz, 5V
- Low noise figure, 2.1 dB @2 GHz, 5V
- Usable to 4.0V
- No external matching components required

## **Typical Applications**

- Base station infrastructure
- Portable Wireless
- CATV & DBS
- MMDS & Wireless LAN
- LTE



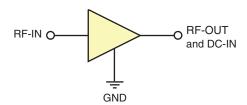
+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

#### **General Description**

PHA-1-D+ (RoHS compliant) is an advanced wideband amplifier die MMIC fabricated using E-pHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PHA-1-D+ has good input and output return loss over a broad frequency range

#### simplified schematic and pad description



Pad	Description
RF-IN	RF input pad. This pad requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	RF output and bias pad. DC voltage is present on this pad; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection.
GND	Connections to ground.

#### Electrical Specifications<sup>1</sup> at 25°C unless noted

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range		0.05		6	GHz
Gain	0.05		17.5		dB
	0.8		15.5		
	2.0		13.6		
	3.0		11.8		
	4.0		10.1		
	6.0		7.4		
nput Return Loss	0.05		11.3		dB
	0.8		16.9		
	2.0		12.5		
	3.0		9.3		
	4.0		8.3		
	6.0		6.5		
Output Return Loss	0.05		13.9		dB
•	0.85		21.3		
	2.0		18.5		
	3.0		14.6		
	4.0		13.1		
	6.0		10.2		
Reverse Isolation	2.0		19.9		dB
Output Power at 1dB Compression	0.05		20.7		dBm
	0.8		22.6		
	2.0		22.5		
	3.0		21.8		
	4.0		21.9		
	6.0		20.9		
Output IP3	0.05		39.7		dBm
	0.8		38.5		
	2.0		38.5		
	3.0		38.4		
	4.0		38.6		
	6.0		36.9		
Noise Figure	0.05		1.7		dB
-	0.8		1.9		
	2.0		2.1		
	3.0		2.3		
	4.0		2.7		
	6.0		3.6		
Supply Operating Voltage (V <sub>DD</sub> )		4.8	5.0	5.2	V
Device Operating Current at V <sub>DD=</sub> 5V		110	155	181	mA
Device Current Variation vs. Voltage			0.058		mA/V
Thermal Resistance, junction-to-ground lead			54		°C/W

<sup>(1)</sup> Electrical Specifications are typical measured characteristics in Mini-Circuits die characterization test board. See Figure 1 for Test Circuit.

## **Absolute Maximum Ratings<sup>2</sup>**

Parameter	Ratings	
Operating Temperature (ground lead)	-40°C to 85°C	
Operating Current at 5V	210 mA	
Power Dissipation	1 W	
Input Power (CW)	+24 dBm	
DC Voltage at RF-OUT Pad (3)	6V	

<sup>2.</sup> Permanent damage may occur if any of these limits are exceeded. These maximum ratings are not intended for continuous normal operations. Die performance measured in industry standard SOT-89 package. 3. For continuous operation, do not exceed 5.2V



### **Characterization Test Circuit**

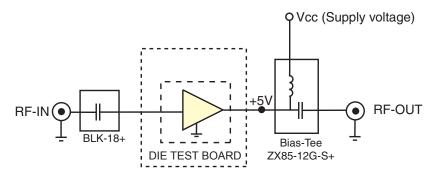


Figure 1: Block Diagram of Test Circuit used for characterization. Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

- 1. Gain and Return loss: Pad= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 5 dBm/tone at output.

#### **Die Layout**

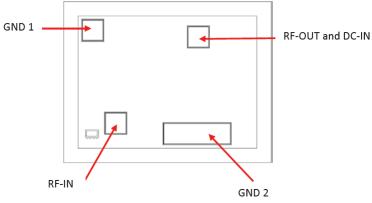


Fig 2. Die Layout

## **Bonding Pad Position**

(Dimensions in µm, Typical)

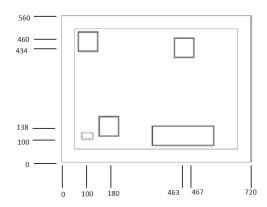


Fig 3. Bonding Pad Positions

#### **Critical Dimensions**

Parameter	Values	
Die Thickness, µm	100	
Die Width, µm	560	
Die Length, μm	720	
Bond Pad Size, µm	80 x 80	
Large Ground Bond Pad Size, µm	80 x 240	

#### **Assembly and Handling Procedure**

#### 1. Storage

Dice should be stored in a dry nitrogen purged desiccators or equivalent.

#### 2. ESD

MMIC Gallium Arsenide (GaAs) amplifier dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static worksta tion. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.

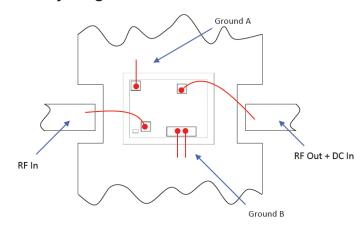
#### 3. Die Attach

The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030Hk-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.

#### Wire Bonding

Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

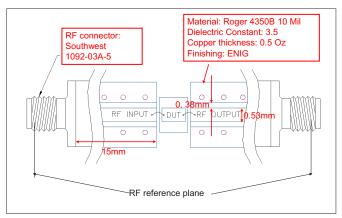
#### **Assembly Diagram**



#### **Recommended Wire Length, Typical**

Wire	Wire Length (mm)	Wire Loop Height (mm)
RF-IN, RF-OUT and DC-IN	0.70	0.15
GROUND A	0.30	0.15
GROUND B	0.60	0.15

## **RF Reference Plane - No port extension**



Additional Detailed Technical Information additional information is available on our dash board.			
	Data Table		
Performance Data	Swept Graphs		
	S-Parameter (S2P Files) Data Set with and without port extension(.zip file)		
Case Style	Die		
Die Ordering and packaging information	Quantity, Package	Model No.	
	Small, Gel - Pak: 10,50,100 KGD*	PHA-1-DG+	
	Medium <sup>†</sup> , Partial wafer: KGD*<5K Large <sup>†</sup> , Full Wafer	PHA-1-DP+ PHA-1-DF+	
mormation	†Available upon request contact sales representative		
	Refer to <u>AN-60-067</u>		
Environmental Ratings	ENV-80		

<sup>\*</sup>Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

## **ESD Rating\*\***

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (>25V) in accordance with ANSI/ESD STM5.2-1999

#### **Additional Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
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<sup>\*\*</sup> Tested in industry standard SOT-89 package.